

# Recent study and results for ionization efficiency theory in pure materials

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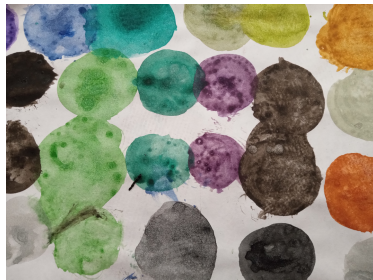


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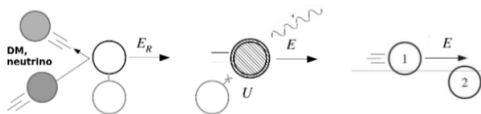


# Nuclear Ionization Efficiency

When a particle interact with a nuclei the energy splits:

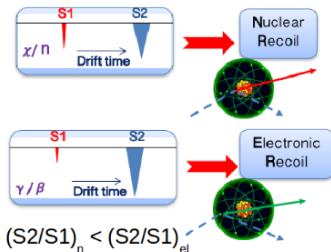
$E_n$  : Nuclear collisions. ( $\bar{v} = C_0 E_n^1$ )

$E_I$  : Ionization (visible) energy [ $\text{keV}_{ee}$ ] ( $\bar{\eta}$ ).



- $$\text{Quenching} = \frac{\text{ionization energy}}{\text{deposited energy}} = f_n = \frac{\bar{\eta}}{\epsilon_R}$$

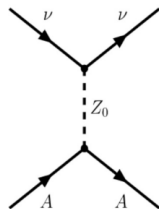
- $\epsilon_R - \bar{\eta} = \bar{v}$ , energy lost to atomic motion
- $u$  is the energy to disrupt the atomic bonding.
- This sets a cascade of slowing-down processes.
- For TPC  $(S2/S1)_n < (S2/S1)_e$ :  $f_n = \frac{(n_e + n_\gamma)_R W}{\epsilon_R}$



<sup>1</sup>Using dimensionless units ( $C_0 = 16.26(1/\text{keV})/Z_1 Z_2 (Z_1^{0.23} + Z_2^{0.23})$ )

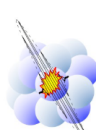
## Coherent elastic Neutrino **Nuclear** Scattering <sup>2</sup>

- 1 Neutral-current process mediated by the Z-boson.
- 2 Low momentum transfer.

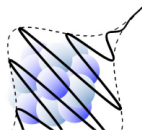


$$\frac{d\sigma}{dT} = \frac{G_F^2 M}{4\pi} \left(1 - \frac{MT}{2E_\nu^2}\right) Q_W^2 \left[F_W(q^2)\right]^2 \quad (1)$$

- 3  $G_F$  Fermi constant,  $T = E_\nu - E'_\nu$  NR energy,  $F_W^2(q^2)$  weak Form Factor,  $M$  target mass and  $Q_W = Z(1 - 4\sin^2 \theta_W) - N$ .



High Q



Low Q

$E < 50$  MeV

<sup>2</sup>D.Z. Freedman, Coherent effects of a weak neutral current, Phys. Rev. D 9 (1974) 1389.

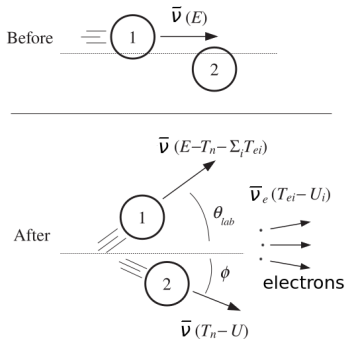
# Lindhard Integral Equation

( $T_n$  : Nuclear kinetic energy and  $T_{ei}$  electron kinetic energy.)

$$\underbrace{\int d\sigma_{n,e}}_{\text{total cross section}} \left[ \underbrace{\bar{v} \left( E - T_n - \sum_i T_{ei} \right)}_A + \underbrace{\bar{v} (T_n - U)}_B + \underbrace{\bar{v} (E)}_C + \underbrace{\sum_i \bar{v}_e (T_{ei} - U_{ei})}_D \right] = 0 \quad (2)$$

## Lindhard's (five) approximations

- I Neglect contribution to atomic motion coming from electrons.
- II **Neglect the binding energy,  $U = 0$ . (Now taken into account)**
- III Energy transferred to electrons is small compared to that transferred to recoil ions.
- IV Effects of electronic and atomic collisions can be treated separately.
- V  $T_n$  is also small compared to the energy  $E$ .



## Lindhard's first order approximation.

$$\underbrace{(k\varepsilon^{1/2})}_{S_e} \bar{v}'(\varepsilon) = \int_0^{\varepsilon^2} \underbrace{dt \frac{f(t^{1/2})}{2t^{3/2}}}_{d\sigma_n} [\bar{v}(\varepsilon - t/\varepsilon) + \bar{v}(t/\varepsilon) - \bar{v}(\varepsilon)],$$

- ❶ Neglects binding energy  $u = 0$ .
- ❷ Only valid for  $\varepsilon \gg u$ .
- ❸ Electronic stopping power assume bare ions.
- ❹  $k\varepsilon^{1/2} > S_e$  for energies  $\varepsilon < 1$ .
- ❶  $u \neq 0$  implies a second order solution.
- ❷ Threshold expected at  $\varepsilon = u$ .
- ❸ Coulomb repulsion effect for  $S_e$  at low energies.

**Lindhard formula**<sup>3</sup> is valid for  $\varepsilon > 1$

LXe  $E_R^{LXe} \approx 1$  MeV and  $E_R^{LAr} \approx 77$  keV

<sup>3</sup>J. Lindhard, et al, Mat. Fys. Med. 33 (1963)

# Improvements for $S_e$

- We use Tilinin model to compute the electronic stopping power.

$$S_e = (\xi_e) N m v \int_R^\infty v_F \sigma_{tr}(v_F) N_e dV, \quad E = \phi_Z(R)$$

- We use data for  $e^-$  atom Momentum Transfer Cross Section (hard-Sphere energy dependent potential model)
- Valid for lower energies compare to Tilinin semi-classical approach.

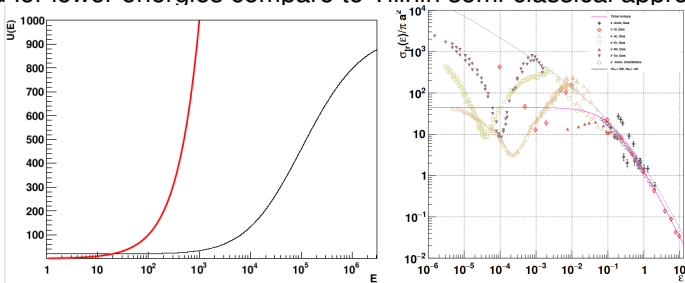


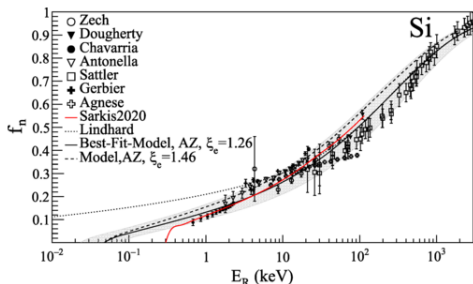
Figure 1: (left) Energy dependent binding energy, (right)  $\sigma_{tr}$  for Ar-e.

# Simplified equation with binding energy

- We are going to use the integro-differential equation for atomic motion deduced in the past work for Si.<sup>4</sup>.

$$-\frac{1}{2}\varepsilon S_e(\varepsilon) \left(1 + \frac{W(\varepsilon)}{S_e(\varepsilon)\varepsilon}\right) \bar{v}''(\varepsilon) + S_e(\varepsilon)\bar{v}'(\varepsilon) = \int_{\varepsilon U}^{\varepsilon^2} dt \frac{f(t^{1/2})}{2t^{3/2}} [\bar{v}(\varepsilon - t/\varepsilon) + \bar{v}(t/\varepsilon - u) - \bar{v}(\varepsilon)], \quad (3)$$

This work have been used for **Skipper CCD's: (DAMIC) PRD 109 (2024) 6, 062007 and (CONNIE) e-Print: 2403.15976.**



- $\xi_e$  from Pauli principle, instead of semi-empirical factor  $\xi_e \approx Z^{1/6}$ .

$$\xi_e^{2/3} \equiv \frac{5}{3} \frac{\int_{k_F-\Delta}^{k_F} E(k) k^2 dk}{E(k_F) \int_{k_F-\Delta}^{k_F} k^2 dk},$$

- $1 < \xi_e < 2.2$

<sup>4</sup>Sarkis, Y. and Aguilar-Arevalo, A. and D'Olivo, J. C, PRA.107.062811

# LAr and LXe

*For LXe the total quanta to low, this motivates new research!*

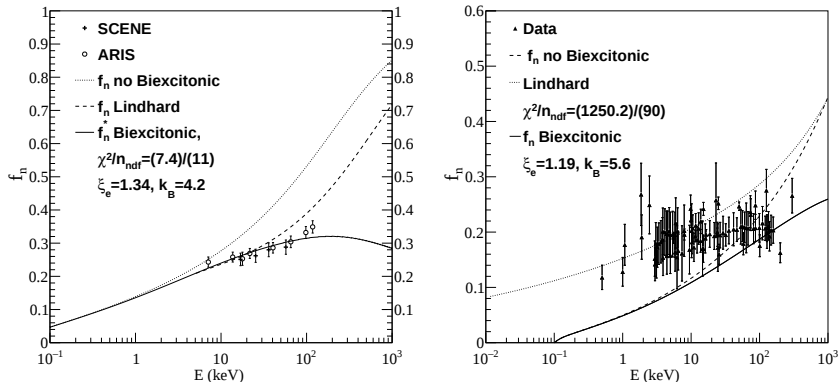
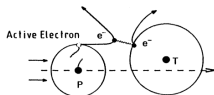
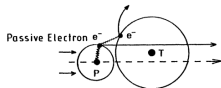


Figure 2: LAr (left) and LXe (right) total quanta.

# Bates-Griffing Process (BG)

- For two atoms collision we take for outer electrons:  $\psi(x'_1, x'_2)_{\pm} = (\psi_1(x'_1)\psi_2(x'_2) \pm \psi_1(x'_2)\psi_2(x'_1))/\sqrt{2}$ .
- This leads to exchange electron non classical potential.
- $\psi(x'_1, x'_2)_{-}$  (triplet): **Passive electrons**, remains in its ground state.



- $\psi(x'_1, x'_2)_{+}$  (singlet): **Active electrons**, electrons are removed.
- Average energy to create an electron from nuclear recoil  $W_i^R = W(1 + N_{ex}/N_i)$  (explain  $W_i^{\alpha} \neq W_i$ ).

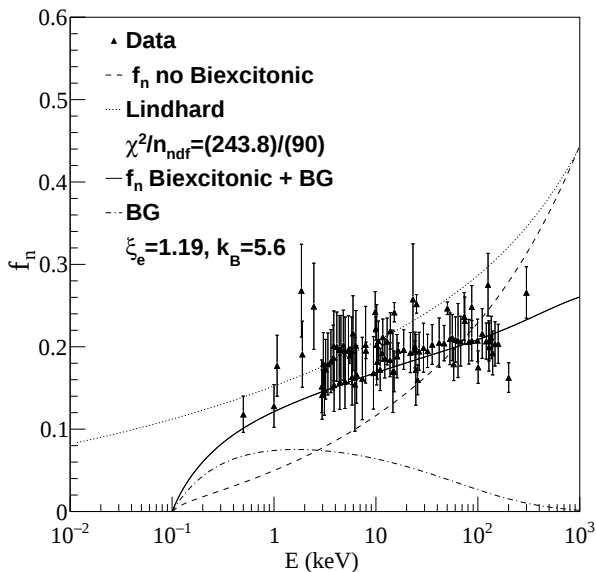


Figure 3: LXe total quanta with BG active effect.

# Thomas-Imel box Model

- Diffusion equation for ions-electrons ( $N_- N_+$ ) Jaffe model, <sup>5</sup>.

$$\frac{\partial N_+}{\partial t} = -\alpha N_- N_+, \quad \frac{\partial N_-}{\partial t} = \mu_e F \frac{\partial N_-}{\partial z} - \alpha N_+ N_-. \quad (4)$$

- Where  $\alpha$  is the recombination factor,  $\mu_e$  electron mobility and  $F$  the TPC electric field.
- Each excited or ionized atom leads to one photon or electron.
- $\Rightarrow N_i + N_{ex} = n_\gamma + n_e$ ,
- $n_e = (1 - r)N_i$  and  $n_\gamma = N_{ex} + rN_i$ .
- Hence, the fraction of ionizations predicted is

$$\frac{n_e}{N_i} = \frac{1}{\xi} \ln(1 + \xi), \quad 1 - r = \frac{1}{\xi} \ln(1 + \xi), \quad \xi = \frac{N_i \alpha}{4a^2 \mu_e F}.$$

$$N_i = \frac{E_R f_n}{W(1 + \beta)}, \quad \text{Where } \beta = N_{ex}/N_i \text{ and } f_n = \frac{E_{ee}}{E_R}.$$

- This recombination model depends on **four parameters for each noble liquid**.

<sup>5</sup>Ann.Phys.IV, V42, pp.303 – 344, (1913). PRA 36, 614 (1987)

# Recombination Parameters from first principles

- Usually <sup>6</sup>, **five to ten parameters** are need.
- **We are just going to use  $\xi_e$  and the scale recombination probability  $\alpha_0$  (universal) as fit parameters.**

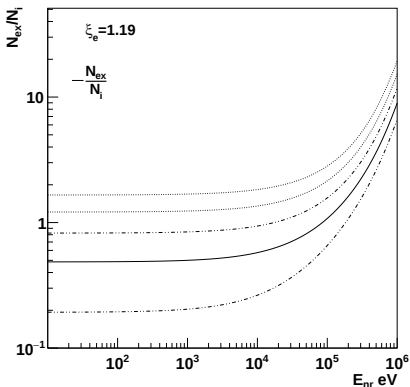
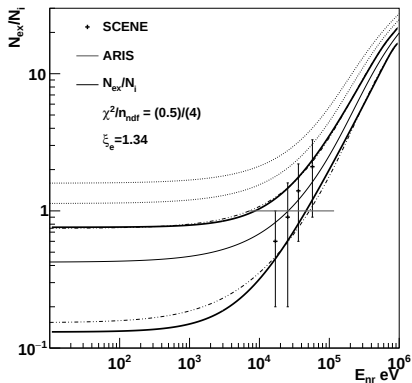
$$\alpha = \alpha_0 Z (2r_W)^2 v_0, \quad \xi = \frac{\alpha_0 N_i Z (2r_W)^2 v_0}{4\mu_e \boxed{(a^2 F)}} \quad (5)$$

- The same inter-atomic potential used for  $f_n$  will explain:
  - Energy and field dependence of the ratio  $N_{ex}/N_i$ .
  - Biexcitonic quenching.
  - Box model length  $a$ , as function of external field.
  - Field dependence of Thomas-Imel Box model parameter:  $\xi \propto F^{-\delta}$ .
  - $\delta_{Ar} \approx (0.4 - 0.6)$  and  $\delta_{Xe} \approx (0.04 - 0.12)$ .

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<sup>6</sup>PRD 100,032002(2019),PRD 91,092007(2015)

We use BG to compute:  $W_i^R = W(1 + \frac{N_{ex}}{N_i})$ .



## Stark Effect for ions inside the Box

- Electric field  $F$  applied to a TPC.
- During recombination we have plasma formed by ions-electrons.
- The polarizability increase significantly  $\varepsilon(k) \gg \varepsilon$
- We can compute the energy correction  $\delta_1$  to the potential

$$e\phi_Z(x, \xi_e) = \langle \psi | V | \psi \rangle,$$

$$\delta_1 = \langle \psi | V_{\text{ext}} | \psi \rangle, \quad V_{\text{ext}} = \pm((\xi_e)^{2/3} ax_z eF) = \pm((\xi_e)^{2/3} axeF) \cos(\theta).$$

- Where  $V_{\text{ext}} \ll \phi_Z(x, \xi_e)$  and  $r \approx r_0 + d\cos(\theta)$ .
- We define the new electron-atom disturbed potential,  
 $\phi_Z^e(x, \xi_e, Z, F) = \phi_Z^e(x, \xi_e, Z, 0) - \delta_1$ .

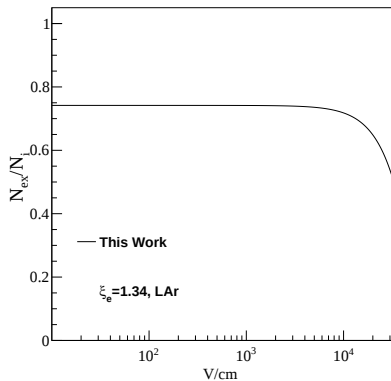
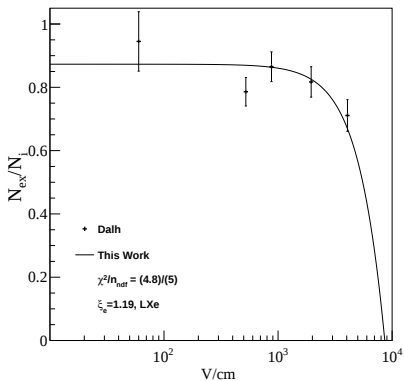
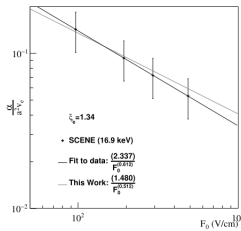
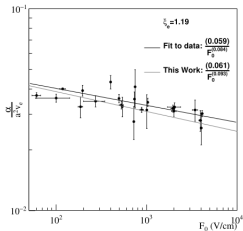
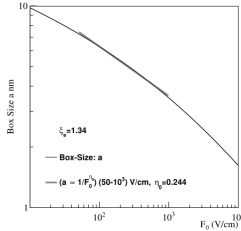
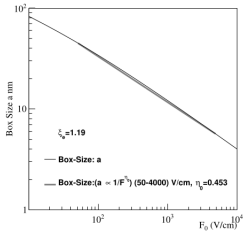


Figure 4:  $N_{\text{ex}}/N_i$  for LXe and LAr as function of the electric field. In LAr predict a breakdown voltage of 60 kV/cm

# Box size



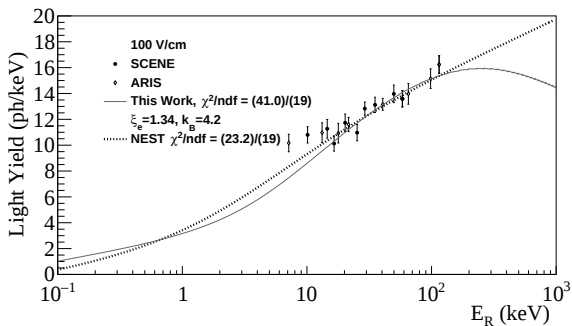
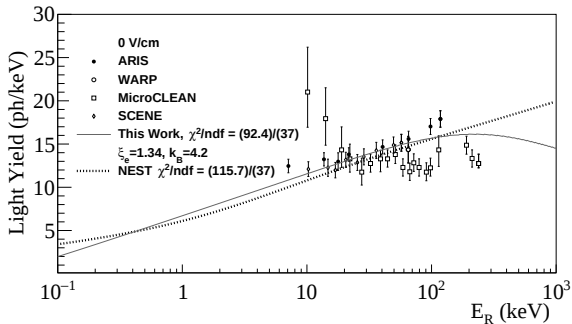
- Using the screen atom potential for ions,

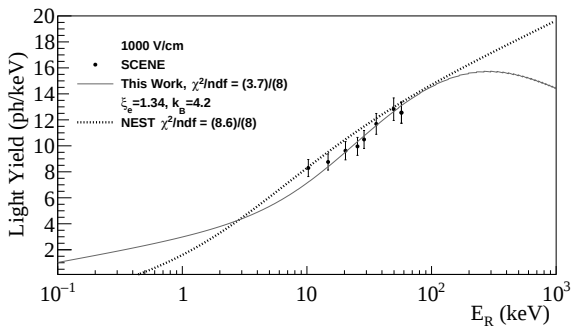
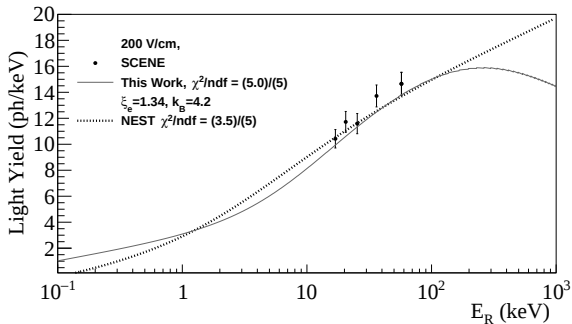
$$-e\phi_Z^e(x', \xi_e, N) = \frac{Ze^2}{bx'} \left[ \left( \frac{N}{Z} \right) (\chi_Z(x') - 1) + 1 \right].$$

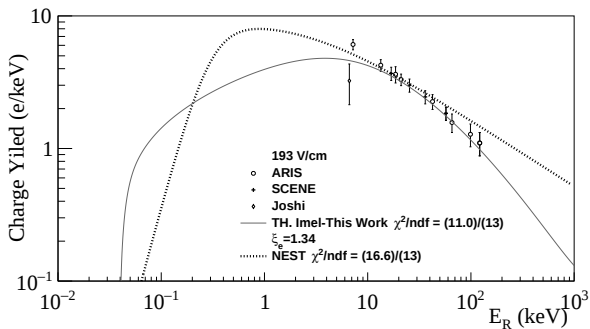
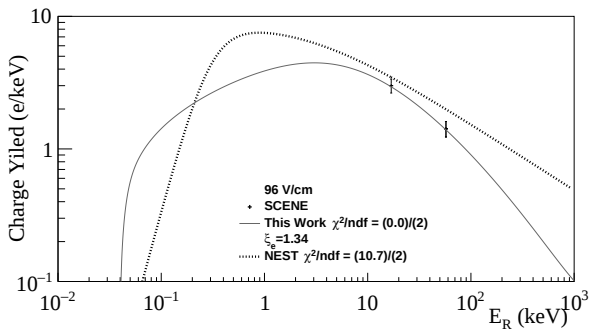
- We can use Dahl electrostatic interpretation for Box size determination,

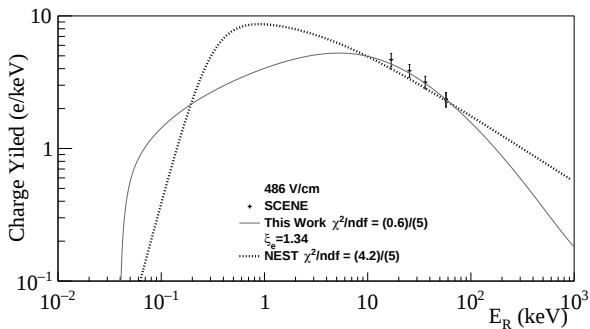
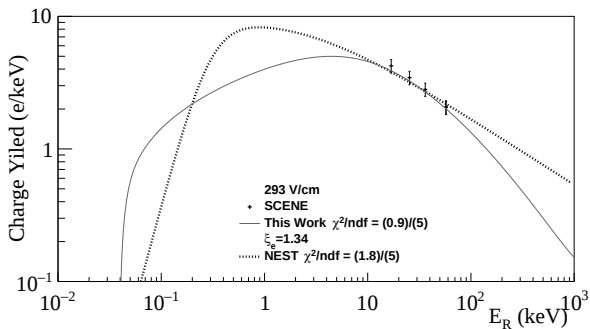
$$-bzF = (\phi_Z^e(z, \xi_e, N))_{sc},$$

- Box size, depends weakly of electric field for high  $Z$ .
- For LNe, LAr, LKr and LXe we have **16 parameters reduced to 1!**









# Conclusions

- We present a first principles approach study based on an integral equation.
- We give a physical interpretation of  $\xi_e$  that allow to describe the  $N_{ex}/N_i$  ratio as function of energy and field.
- With just one parameter,  $\alpha_0$  to describe data in LAr and LXe.  
**Usfull for phenomenology studies.**
- The model for Charge yield have a better match with data at high energies.
- The publications will be available soon with a software to produce outputs too.

Thank you for listening!  
Your feedback will be highly  
appreciated

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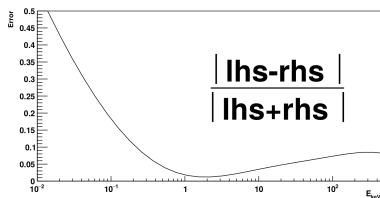
Special thanks to LIDINE organizers for support.

This research was supported in part by SECIHTI grant  
CF-2023-I-1169, and partially by DGAPA-UNAM grants  
PAPIIT-IN106322 and PAPIIT-IT100420 and SNII.

# Backup

# Lindhard QF and Other Works

- Lindhard used a primitive computer(DASK).
- His formula just solved approximately Eq. (3).



- Using Lindhard formula  $\Rightarrow$  Systematic error, large at lower energies.
- Other authors <sup>7</sup>, try to include binding energy.
- But fail to realize in changing the integration limit, reporting nonphysical results.
- One of the achievements of this work is to include in a consistent mathematical and physical way the binding energy.

<sup>7</sup>PHYSICAL REVIEW D 91, 083509 (2015)

# Simplified Integral Equation With Constant Binding Energy with no Straggling

A previous work<sup>a</sup> fail the to defined correctly the lower limit of integration ( $\bar{v}(t/\varepsilon - u)$ ). We take this into account,

$$\boxed{-\frac{1}{2}k\varepsilon^{3/2}\bar{v}''(\varepsilon)} + \underbrace{k\varepsilon^{1/2}\bar{v}'(\varepsilon)}_{S_e} = \int_{\boxed{\varepsilon u}}^{\varepsilon^2} \underbrace{dt \frac{f(t^{1/2})}{2t^{3/2}}}_{d\sigma_n} [\bar{v}(\varepsilon - t/\varepsilon) + \bar{v}(t/\varepsilon - \boxed{u}) - \bar{v}(\varepsilon)] \quad (6)$$

This equation can be solved numerically from  $\varepsilon \geq u$ . The equation predicts a threshold energy of  $u$  ( $\varepsilon_R^{threshold} = 2u$ ).

The equation admits a solution featuring a "kink" at  $\varepsilon = u$  Lower limit of integration  $\varepsilon u \leq t$ , predicts channeling (no atomic movement),

$$\sin \theta / 2 = \sin \psi_{lab} = \sqrt{\frac{U}{E}}.$$

<sup>a</sup>PhysRevD 91 083509 (2015)

# LIDINE2022<sup>8</sup> (Constant Binding Model and $S_e = k\varepsilon^{1/2}$ )

Y. Sarkis et al 2023 JINST 18 C03006

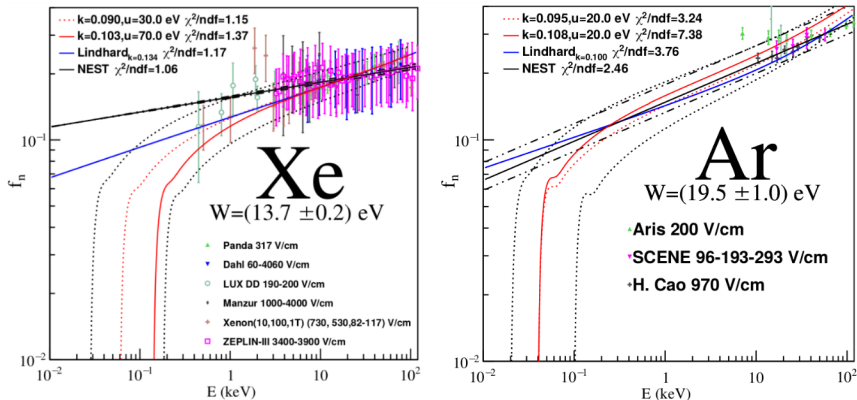


Figure 5: Total quanta for LXe and LAr as a function of the recoil energy.

<sup>8</sup>AstroCeNT (CAMK PAN), Poland